L Number	Hits	Search Text	DB	Time stamp
1	571	(438/15).CCLS.	USPAT;	2003/08/04 12:43
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	5
			IBM_TDB	
2	2	438/15 and (microdisplay or (micro near10 display))	USPAT;	2003/08/04 12:43
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	2	"6330099"	USPAT;	2003/03/26 13:26
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	"6362861"	USPAT;	2002/10/02 10:29
			US-PGPUB;	
			EPO; JPO;	
			DERWENT:	
			IBM_TDB	
_	2231	"Agilent Technologies".AS.	USPAT;	2002/10/02 10:36
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	. 0	"Agilent Technologies".AS. and 349/190	USPAT;	2002/10/02 10:37
	_		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	o	"anistropic etch" adj "filling hole"	USPAT;	2002/10/02 10:46
		dinonopio oto de di minigrati	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
<u>-</u>	o	"anistropic etch" adj "liquid crystal filling hole"	USPAT;	2002/10/02 10:47
-			US-PGPUB;	
			EPO; JPO;	
			DERWENT:	
			IBM TDB	
_	o	"anistropic etch" adj "liquid crystal"	USPAT;	2002/10/02 10:48
		anonopio ottor doj mjana orjetan	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	153	(349/190).CCLS.	USPAT;	2002/10/02 15:20
		`	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
-			IBM_TDB	
_	440	(438/30).CCLS.	USPAT;	2002/10/02 12:46
			US-PGPUB;	1
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1	"anisotropic etch" adj "silicon wafer"	USPAT;	2002/10/02 12:55
		•	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	3	"anisotropic etch" near "silicon wafer"	USPAT;	2002/10/02 12:56
		• • • • • • • • • • • • • • • • • • • •	US-PGPUB;	
			EPO; JPO;	
i l	1		DERWENT;	1
			DEKAAEM	1

-	61	"anisotropic etching" adj "silicon wafer"	USPAT;	2002/10/02 13:14
			US-PGPUB;	, e
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	٠,
_	0	"anisotropic etching" near "liquid crystal"	USPAT;	2002/10/02 13:15
		and any and any and any	US-PGPUB;	
]		EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	0	"anisotropic etching" near "liquid crystal substrate"	USPAT;	2002/10/02 13:15
-		anisotropic etching hear liquid crystal substrate	US-PGPUB;	2002/10/02 13.13
			EPO; JPO;	
			DERWENT;	
	700	Non-to-do-order of the to-the first of the f	IBM_TDB	00004000 40 00
-	708	"anisotropic etching" near "substrate"	USPAT;	2002/10/02 13:23
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	144	(349/154).CCLS.	USPAT;	2002/10/02 13:26
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	10	"injection hole" adj "substrate"	USPAT;	2002/10/02 18:05
		,	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
<u> </u>	0	"sealant" adj "glue, epoxy, solder"	USPAT;	2002/10/02 13:46
-		Sealant adj glue, epoxy, solder	US-PGPUB;	2002/10/02 13:40
			EPO; JPO;	
			DERWENT;	
	İ			
	0	"acalant material" adi "alua, anara, and acldad"	IBM_TDB	2002/40/02 42:46
ļ -	0	"sealant material" adj "glue, epoxy,and solder"	USPAT;	2002/10/02 13:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	311	"sealant" adj "epoxy"	USPAT;	2002/10/02 13:54
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1	_		IBM_TDB	
-	3	"liquid crystal" adj "microdisplays"	USPAT;	2002/10/02 14:22
			US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
-	83	"testing" adj "liquid crystal display"	USPAT;	2002/10/02 14:29
			US-PGPUB;	
1			EPO; JPO;	
-			DERWENT;	
			IBM_TDB	
-	0	"testing" adj "liquid crystal micro display"	USPAT;	2002/10/02 14:27
!			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
-	0	"testing" adj "sealing hole"	USPAT;	2002/10/02 14:29
			US-PGPUB;	
İ			EPO; JPO;	
			DERWENT;	
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-	0	"testing" adj " liquid crystal sealing hole"	USPAT; US-PGPUB;	2002/10/02 14.30
			EPO; JPO;	
			DERWENT;	
		1102200001	IBM_TDB USPAT;	2002/10/02 15:09
-	2	"6330099"		2002/10/02 15.09
,			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	[(0.40,400 4	IBM_TDB	2002/40/02 45:40
-	0	(349/190 and testing).CCLS.	USPAT;	2002/10/02 15:18
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
		0.40/400 adi tootina	USPAT;	2002/10/02 15:18
-	0	349/190 adj testing	US-PGPUB;	2002/10/02 15.16
			EPO; JPO;	
			DERWENT;	
		040/400 magazina	IBM_TDB	2002/10/02 15:10
-	0	349/190 near testing	USPAT;	2002/10/02 15:18
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	_	110 40 44 00 II 114 1	IBM_TDB	2002/10/02 15:18
-	0	"349/190" near "testing"	USPAT;	2002/10/02 15.16
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		HO 40 (400H - 1' H) - 1' - 1 H	IBM_TDB	2002/10/02 15:18
-	0	"349/190" adj "testing"	USPAT;	2002/10/02 15:16
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/40/02 45:24
-	475	(438/15).CCLS.	USPAT;	2002/10/02 15:21
	Ì		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/10/02 16:19
-	98	(injection hole) adj (glue)	USPAT;	2002/10/02 10.19
			US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
		Honotout motorially adi l'avassall	IBM_TDB	2002/10/02 18:20
-	32	"sealant material" adj "epoxy"	USPAT;	2002/10/02 16:30
			US-PGPUB;	
1			EPO; JPO; DERWENT;	
			IBM_TDB	
		"liquid enestel" adi "ecolont material" adi "eneve"	USPAT;	2002/10/02 16:30
-	0	"liquid crystal" adj "sealant material" adj "epoxy"	US-PGPUB;	2002/10/02 10:30
1			EPO; JPO;	
			DERWENT:	
1			IBM_TDB	
· ·		"liquid crystal" adj "sealant material"	USPAT;	2002/10/02 16:31
-	0	iliquiu ciystai auj sealant matenai	US-PGPUB;	2002/10/02 10.31
			EPO; JPO;	
1			DERWENT;	
1			IBM_TDB	
	3	"liquid crystal" near "sealant material"	USPAT;	2002/10/02 16:31
-	3	inquiru ciyotai ileai oealant illatellal	US-PGPUB;	2002/10/02 10.31
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
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2003/03/26 13:35 2003/03/26					
- 21 (liquid adj crystal) near10 (micro adj displays) - 4 liquid adj crystal adj micro-displays - 4 liquid adj crystal adj micro-displays - 7 liquid adj crystal adj micro adj displays) - 1078 (plurality adj holes) near10 substrate - 1078 (plurality adj holes) near10 substrate - 129 (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) adj micro-displays) and (liquid adj crystal) and (liquid adj crystal) adj micro-displays) and (liq	-	7	"6177288"	USPAT;	2002/10/02 18:05
- 21 (liquid adj crystal) near10 (micro adj displays) - 4 liquid adj crystal adj micro-displays - 4 liquid adj crystal adj micro-displays - 7 liquid adj crystal adj micro adj displays - 1078 (plurality adj holes) near10 substrate - 1078 (plurality adj holes) near10 substrate - 129 (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) adj micro-displays) and (liquid adj crystal) adj micro-displays) and (liquid adj crystal) adj micro-displays) and (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) crystal) crystal) near10 (micro adj displays)) and (liquid adj crystal) cr	İ				
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21				DERWENT;	
- 4				IBM_TDB	
- 4 Ilquid adj crystal adj micro-displays SPAT, IBM_TDB	-	21	(liquid adj crystal) near10 (micro adj displays)	USPAT;	2003/03/26 13:35
- 4 liquid adj crystal adj micro-displays - 7 liquid adj crystal adj micro adj displays - 7 liquid adj crystal adj micro adj displays - 1078 (plurality adj holes) near10 substrate - 129 (liquid adj crystal) near10 (injection adj holes) - 129 (liquid adj crystal) near10 (injection adj holes) - 129 (liquid adj crystal) near10 (injection adj holes) - 14 ((liquid adj crystal) near10 (injection adj holes) - 15 ((liquid adj crystal) near10 (injection adj holes) - 16 ((liquid adj crystal) near10 (injection adj holes) - 17 ((liquid adj crystal) near10 (injection adj holes)) - 18 ((liquid adj crystal) near10 (injection adj holes)) - 19 ((liquid adj crystal) near10 (injection adj holes)) - 10 (((liquid adj crystal) near10 (injection adj holes)) - 10 ((((iquid adj crystal) near10 (injection adj holes))) - 10 (((((iquid adj crystal) near10 (injection adj holes))) - 10 (((((iquid adj crystal) near10 (injection adj holes))) - 10 ((((((iquid adj crystal) near10 (injection adj holes))) - 11 ((((((iquid adj crystal) near10 (injection adj injection adj holes))) - 11 ((((((((iquid adj crystal) near10 (injection adj injection adj injection adj holes))) - 11 (((((((((((((((((((((((((((((((((1			US-PGPUB;	
19				EPO; JPO;	
1078			,	DERWENT;	
1078					
US-PGPUB: EPC; JPC; DERWENT; IBM, TDB USPAT; US-PGPUB: EPC; JPC;	-	4	liquid adj crystal adj micro-displays	USPAT;	2003/03/26 13:36
- 1078 Iiquid adj crystal adj micro adj displays EPO: JPO: DERWENT: IBM_TDB USPAT: US-PGPUB: EPO: JPO: JPO: DERWENT: IBM_TDB USPAT: US-PGPUB: EPO: JPO: JPO: JPO: DERWENT: IBM_TDB USPAT: US-PGPUB: EPO: JPO: JPO: JPO: JPO: JPO: JPO: JPO: J					
- 1078 (plurality adj holes) near10 substrate DERWENT, IBM_TDB COS/03/03/26 13:37 COS/05/05/26 13:39 COS/05/05/26 13:30 COS/05/05/05/26 13:30 COS/05/05/05/26 13:30 COS/05/05/05/26 13:30 COS/05/05/05/05/05/05/05/05/05/05/05/05/05/				EPO; JPO;	
1078					
1078		1		IBM TDB	
1078 (plurality adj holes) near10 substrate US-PG-UB; EPO, JPO; DERWENT; IBM TDB USPAT; US-PG-PUB; EPO; J	1 -	7	liquid adi crystal adi micro adi displays		2003/03/26 13:37
1078 Committed EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; E			,,		
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1078 (plurality adj holes) near10 substrate USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB USPAT; US-PGPUB; EPC; JPO; DERWENT; IBM, TDB US-PGPUB; EP					
1078					
- 129 (liquid adj crystal) near10 (injection adj holes) - 129 (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) adj micro-displays) and (liquid adj crystal adj micro adj displays)) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liqui		1078	(plurality adi holes) near10 substrate		2003/03/26 13:40
- 129 (liquid adj crystal) near10 (injection adj holes) - 129 (liquid adj crystal) near10 (injection adj holes) - 0 ((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) near10 (micro adj displays) and (liquid adj crystal) adj micro adj near10 (micro adj displays) near10 (micro adj displays) and (liquid adj crystal) adj micro adj near10 (micro adj displays) and (liquid adj crystal) adj near10 (micro adj displays) and (liquid adj crystal) adj near10 (micr			Annually start in the control of the		
- 129 (liquid adj crystal) near10 (injection adj holes) - 0 ((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal) DERWENT; lb3-PGPUB; EPO; JPO; DERWENT; lb4 TDB USPAT; lb5-PGPUB; EPO; JPO; DERWENT; lb7-PGPUB; EPO; JPO; DERWENT; lb8 TDB USPAT; lb7-PGPUB; lb7-PG	-				
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129					
- 0 ((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro adj displays)) and (liquid adj crystal adj micro adj displays) and ((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal adj micro adj displays)) and (liquid adj crystal adj micro adj displays)) and (liquid adj crystal adj micro adj displays)) and (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) adj micro adj crystal) and ((liquid adj crystal) and (-	120	(liquid adi crystal) near10 (injection adi holes)		2003/03/26 15:34
- 0 ((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal adj micro-displays) and ((liquid adj crystal adj micro adj displays)) and ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) adj micro-displays) and ((liquid adj crystal adj micro-displays)) and ((liquid adj crystal adj micro-displays)) and ((liquid adj crystal adj micro-displays)) and ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) us-pGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT	1	129	(inquid adj crystal) flear to (injection adj floles)		2003/03/20 13.54
- 0 (((((((((((((((((((((((((((((((((((
- 0 ((((()quid adj crystal) near10 (micro adj displays)) and (()quid adj crystal) adj micro-displays) and ((()quid adj crystal) near10 (injection adj holes)) - 4 (((()quid adj crystal) near10 (micro adj displays)) and (()quid adj crystal) near10 (micro adj displays)) and (()quid adj crystal) near10 (micro adj displays)) and (()quid adj crystal) us-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWEN		•			
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displays) and ((liquid adj crystal) near10 (injection adj holes))	-	"			2003/03/20 14.39
- 4 (((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) (uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; IBM_TDB uspAT; uspGPUB; EPO; JPO; DERWENT; uspGPUB; EPO; JPO; DERWENT; uspGPUB; EPO; JPO; DERWENT; uspAGPUB; EPO; JPO; DERWENT; uspGPUB; EPO; JPO; DERWENT; uspAGPUB; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JPO; DERWENT; ePO; JP					
- 4 ((liquid adj crystal) near10 (micro adj displays)) and (liquid adj crystal) micro-displays) and (liquid adj crystal adj micro-displays) and (liquid adj crystal adj micro adj displays)) and ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj uspart; lBM_TDB us			displays) and ((liquid adj crystal) hear to (injection adj noies))		
- 4 (((iquid adj crystal) near10 (micro adj displays)) and ((iquid adj crystal adj micro-displays) and ((iquid adj crystal adj micro adj displays)) - 0 (((iquid adj crystal) near10 (micro adj displays)) and (((iquid adj crystal) near10 (micro adj displays))) - 0 (((iquid adj crystal) near10 (micro adj displays))) - 0 (((iquid adj crystal) near10 (micro adj displays))) - 0 (iquid adj crystal) near10 (micro adj displays)) - 0 (iquid adj crystal) near10 (micro adj displays)) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (iquid adj crystal) near10 (injection adj displays) - 0 (
crystal adj micro-displays) and (liquid adj crystal adj micro adj displays) - 0 ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj CP) JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; ISM_TDB USPAT; US-PGPUB; EPO; J			(/lian.id adi annatal) manufo (miana adi diantana) and (lian.id adi		2002/02/20 44:40
- 0 ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj Crystal) near10 (injection adj holes)) - 7 "6177288" - 8 9392 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer)	-	4			2003/03/26 14:40
- 0 ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IB					
- 0 ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) near10 (injection adj holes)) - 7 "6177288" USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; D			displays)		
- ((liquid adj crystal) near10 (micro adj displays)) and ((liquid adj crystal) near10 (injection adj holes)) - 7 "6177288" USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; ISPGPUB; EPO;					
- 7 "6177288" US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; ISM_TDB USPAT; US-PGPUB					0000/00/00 4 4 50
- 7 "6177288" EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DE	-	0			2003/03/26 14:50
- 7 "6177288" DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-			crystal) near10 (injection adj holes))		
- 9392 (semiconductor adj substrate) near10 (silicon adj wafer) IBM_TDB					
- 9392 (semiconductor adj substrate) near10 (silicon adj wafer) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; ISPO; JPO; DERWENT; JPO; DERWENT; ISPO; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO; DERWENT; JPO;					
- 9392 (semiconductor adj substrate) near10 (silicon adj wafer) US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; E		_			
- 9392 (semiconductor adj substrate) near10 (silicon adj wafer) EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;	-	7	"6177288"		2003/03/26 16:03
- 0 (seal) near10 (glue and epoxy and solder) - 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EP					
- 9392 (seal) near10 (glue and epoxy and solder) - 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) BM_TDB					
- 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;					
- 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;					
- 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;	-	0	(seal) near10 (glue and epoxy and solder)		2003/03/26 15:37
- 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;					
- 9392 (semiconductor adj substrate) near10 (integrated adj circuit) - 1767 (semiconductor adj substrate) near10 (silicon adj wafer) IBM_TDB					
- 9392 (semiconductor adj substrate) near10 (integrated adj circuit) USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;					
- 1767 (semiconductor adj substrate) near10 (silicon adj wafer) US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;					
EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT;	-	9392	(semiconductor adj substrate) near10 (integrated adj circuit)		2003/03/26 15:42
- 1767 (semiconductor adj substrate) near10 (silicon adj wafer) DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;					
- 1767 (semiconductor adj substrate) near10 (silicon adj wafer) IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;		1			
- 1767 (semiconductor adj substrate) near10 (silicon adj wafer) USPAT; US-PGPUB; EPO; JPO; DERWENT;				DERWENT;	
US-PGPUB; EPO; JPO; DERWENT;		1			ļ
EPO; JPO; DERWENT;	-	1767	(semiconductor adj substrate) near10 (silicon adj wafer)	USPAT;	2003/03/26 15:44
DERWENT;					
		1			
IBM_TDB					
				IBM_TDB	

_	3221	(semiconductor adj substrate) near10 (glass)	USPAT; US-PGPUB; EPO; JPO;	2003/03/26 15:47
			DERWENT; IBM_TDB	
1_	7	((semiconductor adj substrate) near10 (integrated adj circuit))	USPAT;	2003/03/26 15:54
-	'	and ((semiconductor adj substrate) near10 (silicon adj wafer))	US-PGPUB;	2003/03/20 15.54
		and ((semiconductor adj substrate) near10 (sincon adj water))	EPO; JPO;	
		direction and advantatory real to (glassy)	DERWENT;	
			IBM TDB	
-	2	6445436.did.	USPAT;	2003/03/26 15:55
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	(micro adj display) near10 (uniform adj image)	USPAT;	2003/03/26 15:57
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
1_	3	(liquid adj crystal adj displays) near10 (uniform adj image)	USPAT;	2003/03/26 15:58
		(qu. a aaj orgotal aaj alopiago) noar ro (alillotti aaj ililago)	US-PGPUB;	2000/00/20 10:00
	1		EPO; JPO;	
]		DERWENT;	
			IBM_TDB	
-	0	"6177288.did."	USPAT;	2003/03/26 16:03
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	2	6177288.did.	IBM_TDB USPAT;	2003/03/26 16:03
-		01/7200.ulu.	US-PGPUB;	2003/03/20 10.03
			EPO; JPO;	•
			DERWENT;	
			IBM_TDB	
-	3	sojourner-douglas.IN. and (micro adj displays)	USPAT;	2003/06/03 09:34
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM_TDB	
_	5875	micro near10 display	USPAT;	2003/06/30 14:08
	00,0	Thiore from to diopidy	US-PGPUB;	2000/00/00 14.00
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	30228	349\$.ccls.	USPAT;	2003/06/30 14:09
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	379	(micro near10 display) and 349\$.ccls.	USPAT;	2003/06/30 14:10
		, , , , , , , , , , , , , , , , , , , ,	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		40 11 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	IBM_TDB	
-	0	(micro near10 display) near10 349\$.ccls.	USPAT;	2003/06/30 14:11
			US-PGPUB;	
			EPO; JPO; DERWENT;	
1			IBM_TDB	
-	477	(manufacturing or making or method) near10 (micro near10	USPAT;	2003/06/30 14:12
		display)	US-PGPUB;	
			EPO; JPO;	
]		DERWENT;	
			IBM_TDB	

-	49	((manufacturing or making or method) near10 (micro near10 display)) and 349\$.ccls.	USPAT; US-PGPUB;	2003/06/30 14:12
			EPO; JPO;	
			DERWENT;	
	2	6562640.did.	IBM_TDB	2002/02/04 40.47
-		0302040.did.	USPAT; US-PGPUB;	2003/08/04 10:17
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	6276	((micro near10 display) or microdisplay)	USPAT;	2003/08/04 10:30
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	312132	liquid near10 crystal	USPAT;	2003/08/04 10:33
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	202	(making or manufactur\$3) near10 (liquid near10 crystal)	USPAT;	2003/08/04 10:36
		near10 (((micro near10 display) or microdisplay))	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM_TDB	
_	319670	semiconductor near10 substrate	USPAT;	2003/08/04 10:39
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	388883	integrated near10 circuit	IBM_TDB USPAT;	2003/08/04 10:42
-	300003	integrated flear to circuit	US-PGPUB;	2003/00/04 10.42
			EPO; JPO;	
			DERWENT;	
	70040	-111	IBM_TDB	0000/00/04 40:45
-	70818	silicon near10 wafer	USPAT; US-PGPUB;	2003/08/04 10:45
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	382	(semiconductor near10 substrate) near10 (integrated near10	USPAT;	2003/08/04 10:48
		circuit) near10 (silicon near10 wafer)	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	((making or manufactur\$3) near10 (liquid near10 crystal)	USPAT;	2003/08/04 10:48
		near10 (((micro near10 display) or microdisplay))) near10 ((semiconductor near10 substrate) near10 (integrated near10	US-PGPUB; EPO; JPO;	
		circuit) near10 (silicon near10 wafer))	DERWENT;	
		The same of the sa	IBM_TDB	
-	2	((making or manufactur\$3) near10 (liquid near10 crystal)	USPAT;	2003/08/04 10:49
		near10 (((micro near10 display) or microdisplay))) and	US-PGPUB;	
		((semiconductor near10 substrate) near10 (integrated near10 circuit) near10 (silicon near10 wafer))	EPO; JPO; DERWENT:	
		Ground freat to (Silicon freat to Water))	IBM_TDB	
-	10929	(semiconductor near10 substrate) and (integrated near10	USPAT;	2003/08/04 10:51
		circuit) and (silicon near10 wafer)	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM_TDB	
-	382	((semiconductor near10 substrate) near10 (integrated near10	USPAT;	2003/08/04 10:52
		circuit) near10 (silicon near10 wafer)) and ((semiconductor	US-PGPUB;	
		near10 substrate) and (integrated near10 circuit) and (silicon	EPO; JPO;	
		near10 wafer))	DERWENT; IBM_TDB	
L	L	I .	םטו_ואוטו	L

-	30494	349\$.ccls.	USPAT;	2003/08/04 10:53
			US-PGPUB;	•)
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	•
-	3	(((semiconductor near10 substrate) near10 (integrated near10	USPAT;	2003/08/04 10:54
		circuit) near10 (silicon near10 wafer)) and ((semiconductor	US-PGPUB;	
		near10 substrate) and (integrated near10 circuit) and (silicon	EPO; JPO;	
		near10 wafer))) and 349\$.ccls.	DERWENT;	
			IBM_TDB	
-	2	"6562640"	USPAT;	2003/08/04 10:55
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	